# **MJL4281A (NPN)** MJL4302A (PNP)

# **Complementary NPN-PNP Silicon Power Bipolar** Transistors

The MJL4281A and MJL4302A are power transistors for high power audio.

## Features

- 350 V Collector-Emitter Sustaining Voltage
- Gain Complementary: Gain Linearity from 100 mA to 5 A High Gain - 80 to 240  $h_{FE} = 50 \text{ (min)} @ I_C = 8 \text{ A}$
- Low Harmonic Distortion
- High Safe Operation Area 1.0 A/100 V @ 1 Second
- High f<sub>T</sub>
- Pb-Free Packages are Available\*

## MAXIMUM RATINGS (T<sub>J</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	350	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	350	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	5.0	Vdc
Collector-Emitter Voltage - 1.5 V	V <sub>CEX</sub>	350	Vdc
Collector Current – Continuous – Peak (Note 1)	Ι <sub>C</sub>	15 30	Adc
Base Current – Continuous	Ι <sub>Β</sub>	1.5	Adc
Total Power Dissipation @ T <sub>C</sub> = 25°C Derate Above 25°C	PD	230 1.84	W °C/W
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	- 65 to +150	°C

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.54	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

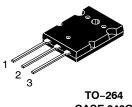
1. Pulse Test: Pulse Width = 5 ms, Duty Cycle < 10%.



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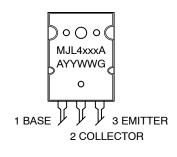
http://onsemi.com

**15 AMPERES** COMPLEMENTARY SILICON POWER TRANSISTORS 350 VOLTS, 230 WATTS



CASE 340G STYLE 2

## **MARKING DIAGRAM**



xxx	= 281 or 302
А	= Assembly Location
YY	= Year
WW	= Work Week

= Pb-Free Package

G

## **ORDERING INFORMATION**

Device	Package	Shipping
MJL4281A	TO-264	25 Units/Rail
MJL4281AG	TO-264 (Pb-Free)	25 Units/Rail
MJL4302A	TO-264	25 Units/Rail
MJL4302AG	TO-264 (Pb-Free)	25 Units/Rail

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

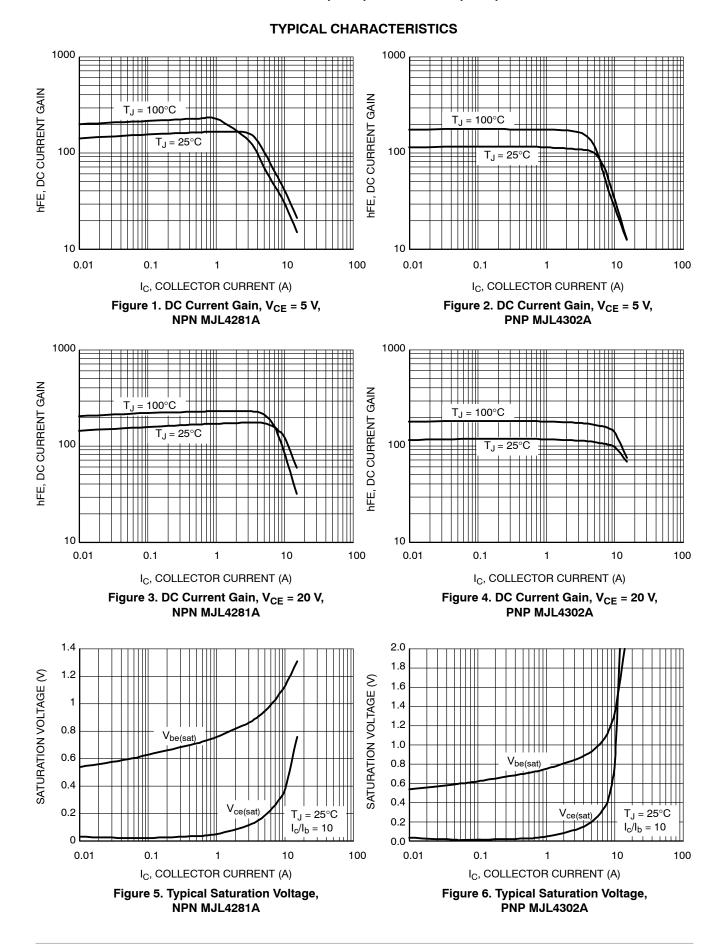
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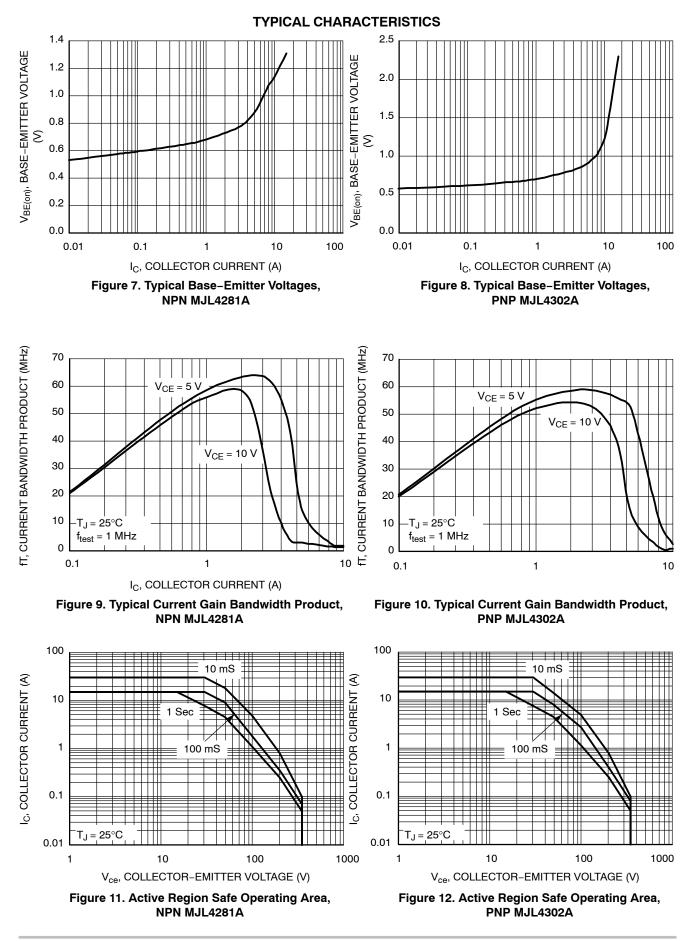
## **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = $25^{\circ}$ C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector Emitter Sustaining Voltage $(I_C = 50 \text{ mA}, I_B = 0)$	V <sub>CE(sus)</sub>	350		Vdc
Collector Cut-off Current $(V_{CE} = 200 \text{ V}, I_B = 0)$	I <sub>CEO</sub>		100	μAdc
Collector Cutoff Current $(V_{CB} = 350 \text{ Vdc}, I_E = 0)$	I <sub>CBO</sub>	_	50	μAdc
Emitter Cutoff Current ( $V_{EB} = 5.0 \text{ Vdc}, I_C = 0$ )	I <sub>EBO</sub>	_	5.0	μAdc
SECOND BREAKDOWN				
Second Breakdown Collector with Base Forward Biased $(V_{CE} = 50 \text{ Vdc}, t = 1.0 \text{ s} (\text{non-repetitive})$ $(V_{CE} = 100 \text{ Vdc}, t = 1.0 \text{ s} (\text{non-repetitive})$	I <sub>S/b</sub>	4.5 1.0		Adc
ON CHARACTERISTICS				
$ \begin{array}{l} DC \ Current \ Gain \\ (I_{C} = 100 \ mAdc, \ V_{CE} = 5.0 \ Vdc) \\ (I_{C} = 1.0 \ Adc, \ V_{CE} = 5.0 \ Vdc) \\ (I_{C} = 3.0 \ Adc, \ V_{CE} = 5.0 \ Vdc) \\ (I_{C} = 5.0 \ Adc, \ V_{CE} = 5.0 \ Vdc) \\ (I_{C} = 8.0 \ Adc, \ V_{CE} = 5.0 \ Vdc) \\ (I_{C} = 15 \ Adc, \ V_{CE} = 5.0 \ Vdc) \\ (I_{C} = 15 \ Adc, \ V_{CE} = 5.0 \ Vdc) \end{array} $	h <sub>FE</sub>	80 80 80 80 50 10	250 250 250 250 - -	_
Collector–Emitter Saturation Voltage $(I_C = 8.0 \text{ Adc}, I_B = 0.8 \text{ Adc})$	V <sub>CE(sat)</sub>	_	1.0	Vdc
Emitter–Base Saturation Voltage $(I_{C} = 8.0 \text{ Adc}, I_{B} = 0.8 \text{ A})$	V <sub>BE(sat)</sub>	_	1.4	Vdc
Base-Emitter ON Voltage $(I_C = 8.0 \text{ Adc}, V_{CE} = 5.0 \text{ Vdc})$	V <sub>BE(on)</sub>	_	1.5	Vdc
DYNAMIC CHARACTERISTICS				
Current–Gain – Bandwidth Product ( $I_C = 1.0 \text{ Adc}, V_{CE} = 5.0 \text{ Vdc}, f_{test} = 1.0 \text{ MHz}$ )	fT	35	_	MHz
Output Capacitance $(V_{CB} = 10 \text{ Vdc}, I_E = 0, f_{test} = 1.0 \text{ MHz})$	C <sub>ob</sub>	-	600	pF

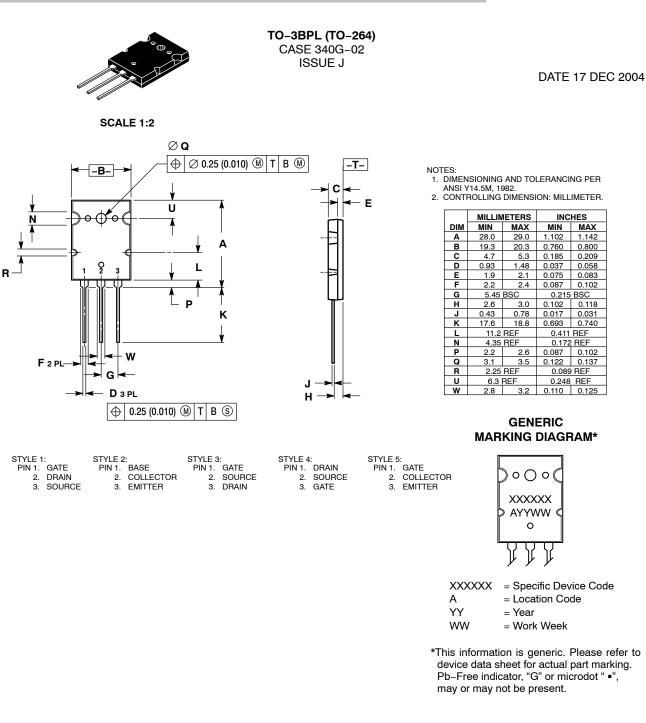
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